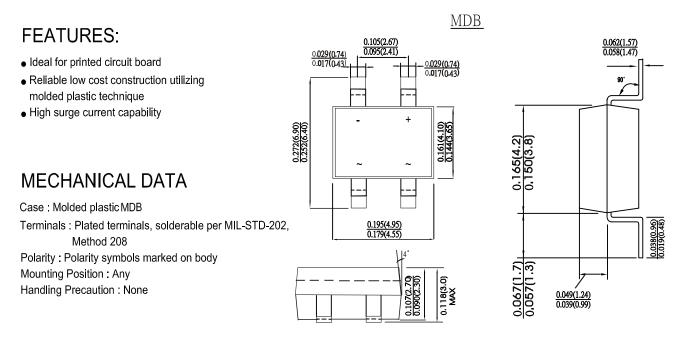
# BACO SEMICONDUCTOR CO., LTD. MDB01G THRU MDB07G

### SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIER



Dimension in inches and (millimeters)

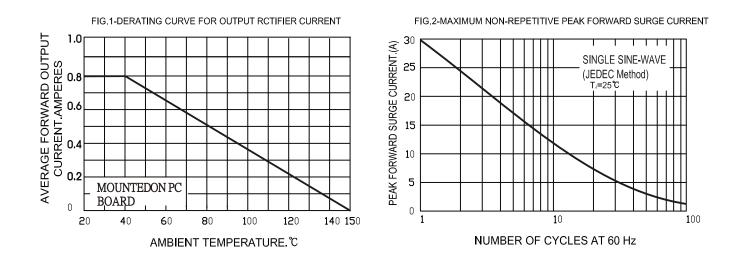
#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25  $^{\circ}$ C ambient temp. temperaturl unless otherwise specified. Single phase, half sine, wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20 %.

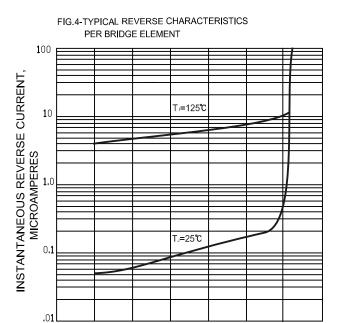
CHARACTERISTIC	SYMBOL	MDB 01G	MDB 02G	MDB 03G	MDB 04G	MDB 05G	MDB 06G	MDB 07G	UNITS
Maximum recurrent peak reverse voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current at Ta=40℃ -on glass-expoxy P.C.B. -on aluminum substrate	I(AV)	0.5 0.8				Amps			
Peak forward surge current 8.3mm single half sine-wave superimposed on rated load(JEDEC Method)	IFSM	30			Amps				
Maximum instantaneous forward voltage @0.5 A	VF	1.0				Volts			
Maximum DC reverse currentTa= $25^{\circ}$ Cat rated DC blocking voltageTa= $125^{\circ}$ C	IR	5.0 500.0				μA			
Operating junction ,and storage temperature range	TJ,TSTG	-55 to +150			°C				



#### RATINGS AND CHARACTERISTIC CURVES



	FI 10 =	FIG.3-TYPICAL FORWARD CHARACTERISTICS PER BRIDGE ELEMENT								
	E									
	F									
КR	F									
L L L	F						1			
ð	1									
VAF VAF	, E									
N U	Ì			1/						
				/	TJ=25℃					
INSTANTANEOUS FORWARD CURRENT, AMPERES 10 III				PULSE WIDTH=300 µ S						
й z	0.1		/		1% 0011 0					
ITA	F		/							
IAN	F						1			
-SN	F									
-	Γ									
	0.0 <b>1</b> L						J			
	0.	.4	0 <b>.6</b>	0 <b>.8</b>	<b>1.</b> 0	1.2	1.4			
		INSTAN	FANEOUS	FORWARD	O VOLTAGI	E. VOLTS				



0

PERCENT OF RATED PEAK REVERSE VOLTAGE, %

0

0

0

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